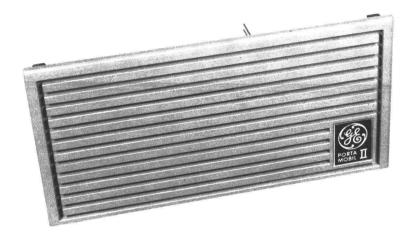


# $\textbf{Porta-Mobile} \, \boldsymbol{I}^{\scriptscriptstyle{\mathsf{TM}}}$

# AUDIO POWER AMPLIFIER 19C321258G1, G3 AND G4



# **SPECIFICATIONS** \*

USED WITH:

PL NUMBER

19C321258G1&G4

19C321258G3

AUDIO POWER INPUT

SPEAKER IMPEDANCE

FREQUENCY RESPONSE

DISTORTION

PMII

AUDIO POWER OUTPUT

10 Watts (@ rated audio)

1/2 Watt (@ rated audio)

500 milliwatts (@ rated audio)

8 ohms

300 to 3000 Hz  $\pm 4$  dB (1000 Hz reference)

Less than 10%

\*These specifications are intended primarily for the use of the serviceman. Refer to the appropriate Specification Sheet for the complete specifications.

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WARNING ---

Although the highest DC voltage in PORTA-MOBIL II TM Equipment is supplied by a portable or vehicular battery, high currents may be drawn under short circuit conditions. These currents can possibly heat metal objects such as tools, rings, watchbands, etc., enough to cause burns. Be careful when working near energized circuits! High-level RF energy in the transmitter Power Amplifier assembly can cause RF burns upon contact. Keep away from these circuits when the transmitter is energized!

# **DESCRIPTION**

Audio Power Amplifier 19C321258 groups 1, 3 and 4, is constructed in the front cover for the PMII case assembly. Amplifier groups 1 and 4 provide 10 Watts audio power output, and group 3 provides 1/2 Watt audio power output. Amplifier groups 1 and 4 consist of a power amplifier circuit, audio mute circuit and a 7.5 volt regulator circuit. Group 3 consists of a 7.5 volt regulator and a speaker.

# CIRCUIT ANALYSIS

#### Amplifier

Receiver audio output interfaces with the audio power amplifier through the system board and connects to P1501-4 (AUD IN HI). Receiver audio is coupled through transformer T1 to the base of power transistors Q3 and Q4. Power transistors Q3 and Q4 are part of a class B common emitter amplifier circuit with a transformer input and a transformer output. Thermistor RT1 in the emitter bias circuit provides temperature compensation for audio power output stability. The collector output is coupled through audio power transformer T1501. Transformer T1501 has a tap for 10 Watts operation connected to P1501-8 (AUD OUT HI 10 W).

# Audio Mute

The audio mute circuit consist of transistors Q1 and Q2. Transistor Q2

completes the negative path for the primary and secondary of transformer T1. When a positive DC voltage level from the receiver audio PA is present at P1501-7 (AUD SQ. MUTE) and coupled through Q1 to the base of Q2, Q2 conducts completing the negative path and full audio is heard from the speaker. When the DC voltage level at P1501-7 drops, Q2 stops conducting as hard and the audio is muted.

## 7.5 Volt Regulator

The 7.5 Volt Regulator circuit provides a continuous and keyed 7.5 volts for the operation of the transmitter, receiver, and tone and control options. The regulator circuit consists of pass transistor Q5 and regulator module A1. A typical regulator circuit is shown in Figure 1.

The 10-Volt supply is connected to P1501-12 and is applied to the emitter of pass transistor Q5. The collector voltage of Q5 is held at 7.5 Volts by regulator transistors Q1 and Q2. If the collector voltage of Q5 starts to increase above 7.5 Volts, Q2 will conduct harder causing the bias on the base of Q1 to decrease. Q1 will conduct less causing Q5 to conduct less to hold the collector voltage at 7.5 Volts. If the collector voltage of Q5 starts to decrease below 7.5 Volts, Q2 will conduct less causing Q1 to conduct harder. Q1 conducting harder causes Q5 to conduct harder to again hold the collector voltage of Q5 at 7.5 Volts.

Transistors Q3 and Q4 provides a keyed +7 Volts for the transmitter power control circuit. When the PTT switch is pushed the

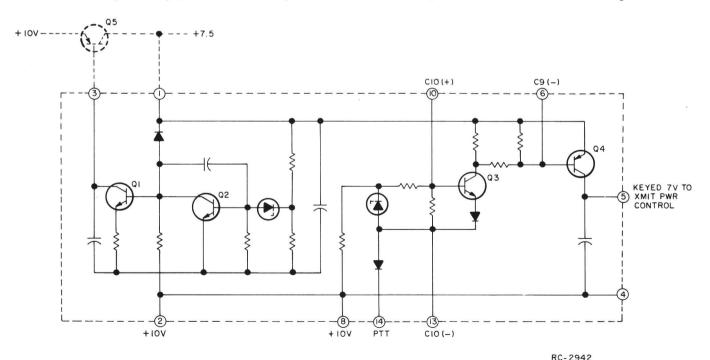


Figure 1 - Typical Regulator Circuit

emitter circuit of transistor Q3 is completed and Q3 conducts. Q3 conducting causes the bias on the base of NPN transistor Q4 to go low. The bias on Q4 going

low causes Q4 to conduct. Q4 conducting places regulated +7 Volts on Pin 5 of the regulator module and P1501-13 (7.5 V Tx KEYED).

# **TROUBLESHOOTING**

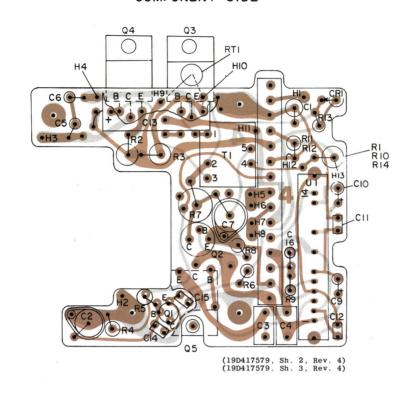
Should a service problem arise, the following  $\operatorname{Quick-Checks}$  can assist the service technician.

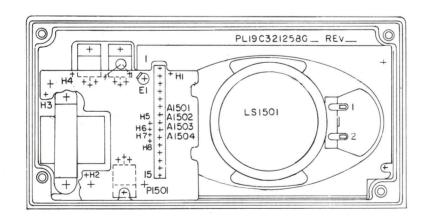
SYMPTOM	CHECK FOR:
1. No Audio	<ol> <li>+10 Volts at P1501-5.</li> <li>Receiver audio at P1505-4.</li> <li>Defective power transistor Q3 or Q4.</li> </ol>
2. Low Audio	<ol> <li>DC voltage at P1505-7.</li> <li>Defective audio mute transistors Q1 and Q2.</li> <li>Defective C1, C2 or C7.</li> </ol>
3. No regulated 7.5 Volts	<ol> <li>+10 Volts at P1501-12.</li> <li>Defective C8, C9 or C10.</li> <li>Defective Q5.</li> <li>Defective A1.</li> </ol>

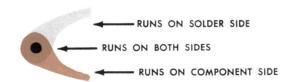
MOBILE RADIO DEPARTMENT
GENERAL ELECTRIC COMPANY • LYNCHBURG, VIRGINIA 24502

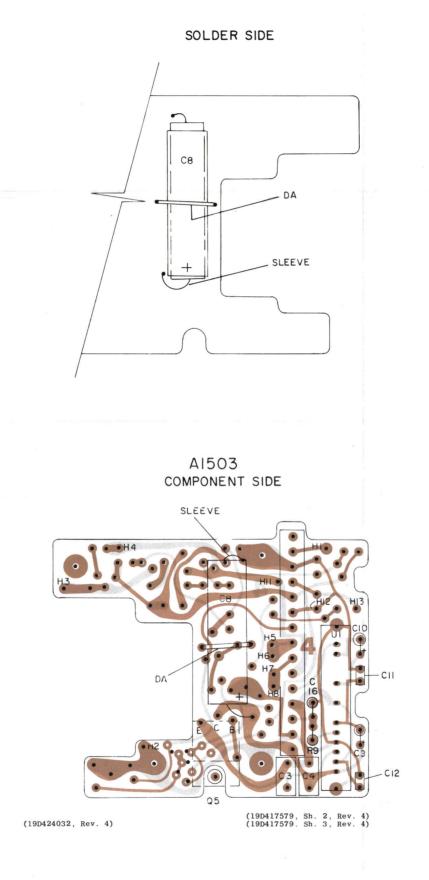


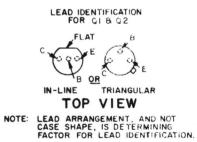
# COMPONENT SIDE







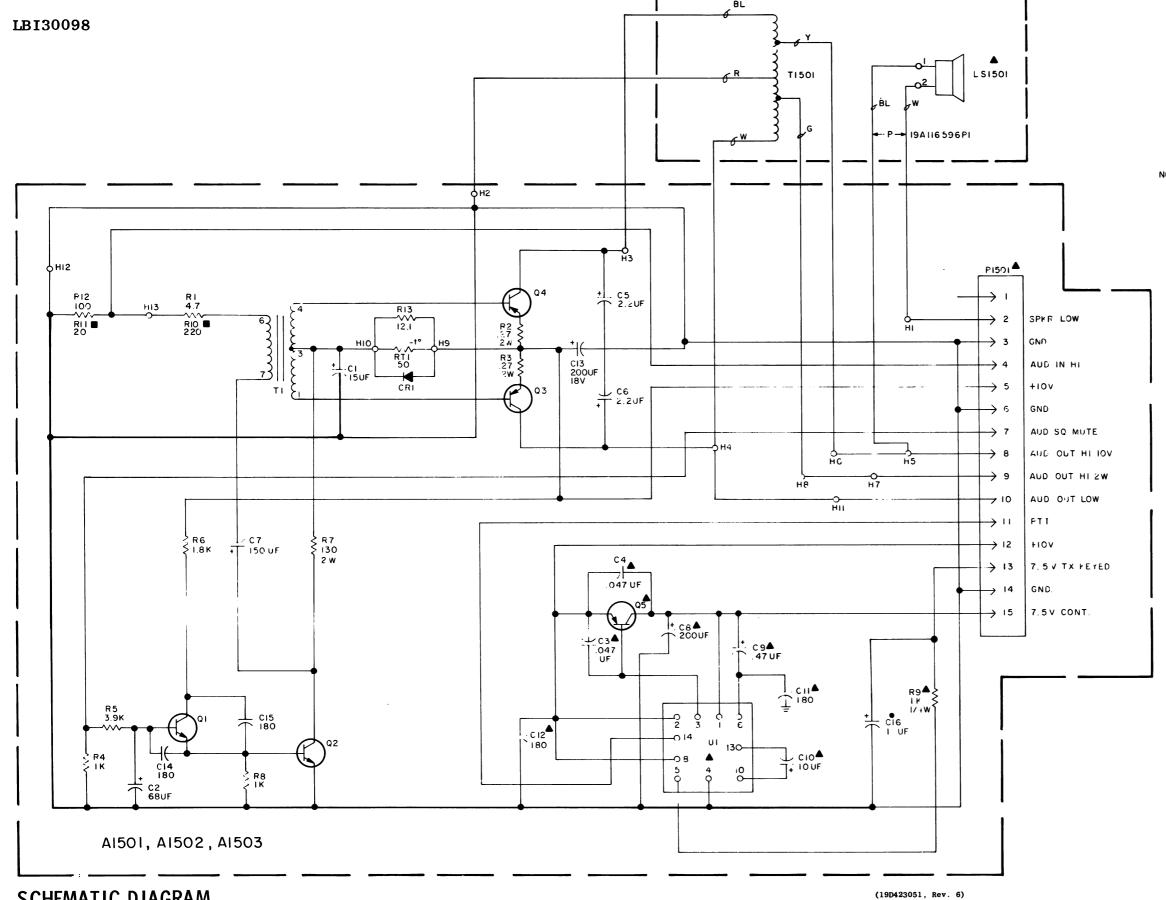




OUTLINE DIAGRAM

AUDIO POWER AMPLIFIER

Issue 3



- NOTES:
  I. COMPONENTS MARKED THUS "A" ARE USED WITH ALL
  OTHER COMPONENTS TO MAKE UP GROUPS I & 2, BUT ARE ONLY ONES PRESENT IN GROUP 3.
- 2. ADD JUMPERS BETWEEN HOLES 6 & 13 AND HOLES II & 12 IN GROUP 3 ONLY.
- 3. " USED IN GROUP 2 ONLY.
- 4. ". NOT PRESENT IN LOW BAND UNITS.

ALL RESISTORS ARE 1/2 WATT UNLESS OTHERWISE SPECIFIED AND RESISTOR VALUES IN OHMS UNLESS FOLLOWED BY K=1000 OHMS OR MEG = 1,000,000 OHMS OCAPACITOR VALUES IN PICOFARADS (EQUAL TO MICROMICROFARADS, INDUCTANCE VALUES IN MICROHENRYS UNLESS FOLLOWED BY UF= MICROFARADS, INDUCTANCE VALUES IN MICROHENRYS UNLESS FOLLOWED BY MH= MILLIHENRYS OR H= HENRYS.

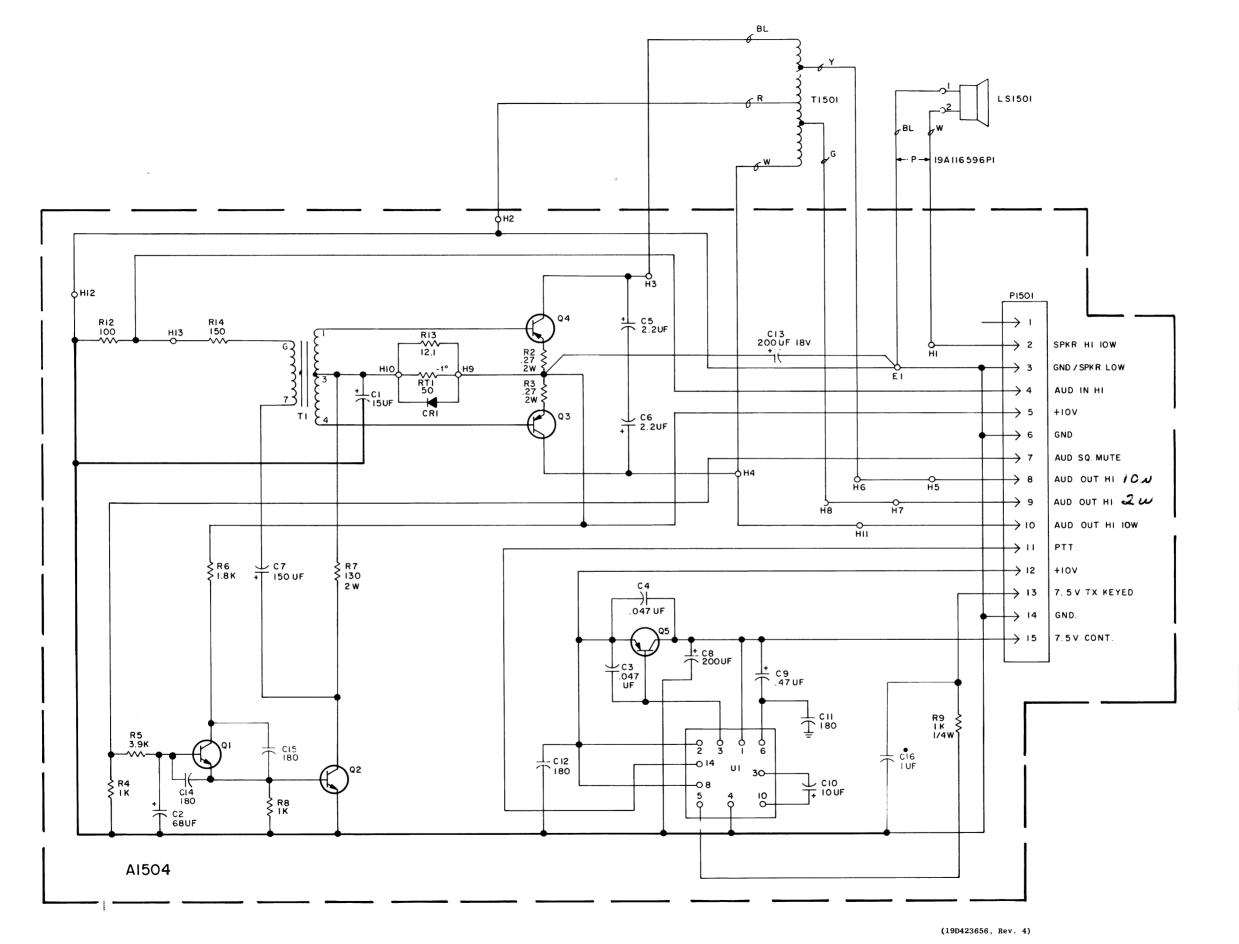
IN ORDER TO RETAIN RATED EQUIPMENT PERFORMANCE, REPLACEMENT OF ANY SERVICE PART SHOULD BE MADE ONLY WITH A COMPONENT HAVING THE SPECIFICATIONS SHOWN ON THE PARTS LIST FOR THAT PART.

MODEL NO.	REV LETTER
PL19C321258G1	
PL19C321258G2	
PL19C321258G3	
PL 19C321265G1	В
PL19C321265G2	В
PL19C321265G3	В

SCHEMATIC DIAGRAM

AUDIO POWER AMPLIFIER 19C321258G1 & G3

Issue 3



NOTE:

I. . NOT PRESENT IN LOW BAND UNITS.

ALL RESISTORS ARE 1/2 WATT UNLESS OTHERWISE SPECIFIED AND RESISTOR VALUES IN OHMS UNLESS FOLLOWED BY K=1000 OHMS OR MEG=1,000,000 OHMS CAPACITOR VALUES IN PICOFARADS (EQUAL TO MICROMICROFARADS) UNLESS FOLLOWED BY UF= MICROFARADS, INDUCTANCE VALUES IN MICROHENRYS UNLESS FOLLOWED BY MH= MILLIHENRYS OR H=HENRYS.

IN ORDER TO RETAIN RATED EQUIPMENT PERFORMANCE, REPLACEMENT OF ANY SERVICE PART SHOULD BE MADE ONLY WITH A COMPONENT HAVING THE SPECIFICATIONS SHOWN ON THE PARTS LIST FOR THAT PART.

MODEL NO. REV LETTER
PL19C321258G4
3L19C321265G4
B

SCHEMATIC DIAGRAM

AUDIO POWER AMPLIFIER 19C321258G4

Issue 3

# LBI30098

#### PARTS LIST

LB130099B

FRONT COVER AND AUDIO AMPLIFIER BOARD 19C321258G1, G3, G4

SYMBOL	GE PART NO.	DESCRIPTION
A1501, A1503, A1504		AUDIO AMPLIFIER BOARD A1501 19C321265G1 A1503 19C321265G3 A1504 19C321265G4
Cl	5496267P14	Tantalum: 15 $\mu\text{f}$ ±20%, 20 VDCW; sim to Sprague Type 150D.
C2	5496267P11	Tantalum: 68 $\mu$ f $\pm 20\%$ , 15 VDCW; sim to Sprague Type 150D.
C3 and C4	19A116080P105	Polyester: 0.047 μf ±10%, 50 VDCW.
C5 and C6	5496267P13	Tantalum: 2.2 $\mu$ f $\pm 20\%$ , 20 VDCW; sim to Sprague Type 150D.
C7	5496267P12	Tantalum: 150 $\mu$ f $\pm 20\%$ , 15 VDCW; sim to Sprague Type 150D.
C8	19A115680P26	Electrolytic: 200 $\mu$ f +150% -10%, 18 VDCW; sim to Mallory Type TTX.
C9	5491674P27	Tantalum: .47 $\mu$ f $\pm$ 20%, 35 VDCW; sim to Sprague Type 162D.
C10	5491674P37	Tantalum: 10 $\mu$ f $\pm$ 20%, 10 VDCW; sim to Sprague Type 162D.
Cll and Cl2	19A116114P10073	Ceramic: 180 pf ±10%, 100 VDCW; temp coef -3300 PPM.
C13*	19A115680P10	Electrolytic: 200 µf +150% -10%, 18 YDCW; sim to Mallory Type TTX. Added to G1 by REV A.
C14* and C15*	19A116114P10073	Ceramic: 180 pf ±10%, 100 VDCW; temp coef -3300 PPM. Added by REV A.
C16*	5491674Pl	Tantalum: 1.0 $\mu$ f +40-20%, 10 VDCW; sim to Sprague Type 162D. Added by REV A.
		DIODES AND RECTIFIERS
CR1	4037822P1	Silicon, 1000 mA, 400 PIV.
Q1	19A115910P1	Silicon, NPN; sim to Type 2N3904.
Q2	19A115300P4	Silicon, NPN.
Q3	19A130324G2	Silicon, PNP. (Includes RT1).
Q4 and Q5	19A116942P1	Silicon, PNP.
		RESISTORS
R1	7147161P13	Composition: 4.7 ohms ±5%, 1/2 w.
R2 and R3	19B209022P101	Wirewound: .27 ohm $\pm 10\%$ , 2 w; sim to IRC Type BWH.
R4	3R77P102K	Composition: 1K ohms ±10%, 1/2 w.
R5	3R77P392J	Composition: 3.9K ohms ±5%, 1/2 w.
R6	3R77P182K	Composition: 1.8K ohms ±10%, 1/2 w.
R7	3R79P131J	Composition: 130 ohms ±5%, 2 w.
R8	3R77P102K	Composition: 1K ohms ±10%, 1/2 w.
R9	3R152P102K	Composition: 1K ohms ±10%, 1/4 w.
R12	3R77P101J	Composition: 100 ohms ±5%, 1/2 w.
R12	19C314256P31219	Metal film: 12.1 ohms ±1%, 1/2 w.
R14	3R77P151J	Composition: 150 ohms ±5%, 1/2 w.

	SYMBOL	GE PART NO.	DESCRIPTION
	RT1	5490828P54	Thermistor: 50 ohms ±10%, color code blue; sim to Carborundum Type B08073-16. (Part of Q3).
]	Tl	19A134159P1	Audio freq: 300-4000 Hz, Pri: 5.7 ohms ±15%, Sec: 10.7 ohms max.
	U1+	19D417627G3	INTEGRATED CIRCUITS Regulator: 7.5 volt. Earlier than REV A:
		19D417627G2	Regulator: 7.5 volt.
	E1	7878455P2	Terminal, lug.
	P1501	19A116659P70	Connector, printed wiring: 15 contacts.
	T1501	19A134167P1	Audio freq: 300-4000 Hz, 0.33 ohms DC res at 25 ±3°C non-operating.
			FRONT COVER 19C321253G1
	LS1501	19B209541P1	Permanent magnet: 3 x 5 inch, 8 ohms ±10% imp, at 0.5 watt input; sim to Oaktron T-4014.
		19A121175P29 4036555P1 19A134542P1 19D417614P1 19B226409P1 NP279872 19A134343P1 19B226372P1 19A134016P1 19A116023P1	Insulator. (Used with C8). Insulator, washer: nylon. (Used with Q2). Cover gasket. Grille plate. Spacer. Nameplate. (GE MONOGRAM). Washer, non metallic. Clip. (Secures LS1501). Insulator, bushing. (Used with Q3, Q4 on A1501, A1503, A1504). Insulator, plate. (Used with Q3, Q4 on A1501, A1503, A1504).
			÷.

\*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES.

## PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

## REV. A - Audio Amplifier Board 19C321265G1

To make compatible for motorcycle application. Added C13, C14, C15 and C16.

#### REV. A - Audio Amplifier Board 19C321265G3

To make compatible for motorcycle application. Added C16.

#### REV. A - Audio Amplifier Board 19C321265G4

To make compatible for motorcycle application. Added Cl4, Cl5 and Cl6.

# REV. B - Audio Amplifier Board Gl, 3 & 4

To improve transmitter stability.
Added C16. Also, added note:
● Not present in low band units.

